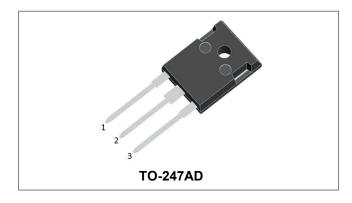


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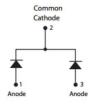
MBR80150WT SCHOTTKY RECTIFIER



Features

- 150 °C T_J operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|--|--|---|-------------------------------|-------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | - | 150 | V |
| Average Rectified Forward Current | I _{F (AV)} | 50% duty cycle @Tc=125°C, rectangular wave form | 40(Per Leg) 80(Per Device) | Α |
| Peak One Cycle Non-Repetitive Surge Current(Per Leg) | I _{FSM} | 8.3ms, Half Sine pulse | 90 | Α |

Electrical Characteristics:

| Characteristics | Symbol | Condition | Тур. | Max. | Units |
|---------------------------------|-----------------|--|------|--------|-------|
| Forward Voltage Drop(Per Leg) * | V _{F1} | @ 40A, Pulse, T _J = 25 °C | - | 0.90 | V |
| | V _{F2} | @ 40A, Pulse, T _J = 125 °C | - | 0.75 | V |
| Reverse Current (Per Leg) * | I _{R1} | @V _R = rated VR | - | 2 | mA |
| | | T _J = 25 °C | | | |
| | I _{R2} | @V _R = rated VR | - | 40 | mA |
| | | T _J = 125 °C | | | |
| Junction Capacitance(Per Leg) | Ст | @V _R = 5V, T _C = 25 °C | - | 1800 | pF |
| | | f _{SIG} = 1MHz | | | |
| Voltage Rate of Change | dv/dt | - | - | 10,000 | V/μs |

^{*} Pulse width < 300 μs, duty cycle < 2%

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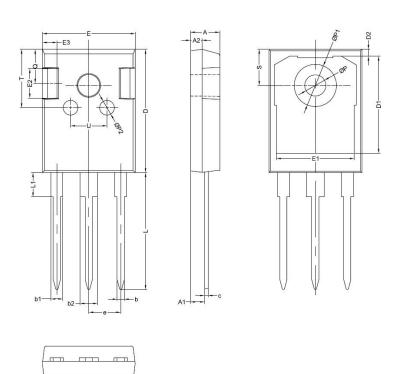




Thermal-Mechanical Specifications:

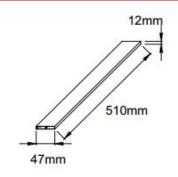
| Characteristics | Symbol | Condition | Specification | Units |
|---|-------------------|--------------|---------------|-------|
| Junction Temperature | TJ | - | -55 to +150 | °C |
| Storage Temperature | T _{stg} | - | -55 to +150 | °C |
| Typical Thermal Resistance Case to heatsink | R _{θJCH} | DC operation | 0.25 | °C/W |
| Approximate Weight | wt | - | 6.28 | g |
| Case Style | TO-247AD | | | |

Mechanical Dimensions TO-247AD

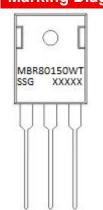


| OVMDOL | Millimeters | | | | |
|-------------|-------------|-------|-------|--|--|
| SYMBOL | MIN. | TYP. | MAX. | | |
| Α | 4.80 | 5.00 | 5.20 | | |
| A1 | 2.20 | 2.41 | 2.61 | | |
| A2 | 1.90 | 2.00 | 2.10 | | |
| b | 1.10 | 1.20 | 1.40 | | |
| b1 | 1.80 | 2.00 | 2.20 | | |
| b2 | 2.80 | 3.00 | 3.20 | | |
| С | 0.50 | 0.60 | 0.75 | | |
| D | 20.30 | 21.00 | 21.20 | | |
| D1 | | 16.55 | | | |
| D2 | | 1.20 | | | |
| E | 15.45 | 15.80 | 16.00 | | |
| E1 | | 13.30 | | | |
| E2 | | 5.00 | | | |
| E3 | | 2.50 | | | |
| е | | 5.44 | | | |
| L | 19.42 | 19.92 | 20.70 | | |
| L1 | | 4.13 | | | |
| Р | 3.50 | 3.60 | 3.70 | | |
| P1 | 7.1 | | 7.40 | | |
| P2 | | 2.50 | | | |
| Q | | 5.80 | | | |
| Q S T | 6.05 | 6.15 | 6.25 | | |
| | | 10.00 | | | |
| U | | 6.20 | | | |

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

MBR = Device Type 80 = Forward Current (80A) 150 = Reverse Voltage (150V) WT = Configuration

Cautions: Molding resin

Epoxy resin UL:94V-0

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Ordering Information:

| Device | Package | Shipping | |
|------------|-------------------|--------------|--|
| MBR80150WT | TO-247AD(Pb-Free) | 25pcs / tube | |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
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